



40V N-Channel Enhancement Mode MOSFET

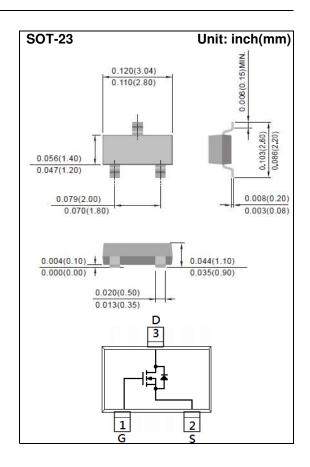
Voltage 40 V Current 4.3A

Features

- $R_{DS(ON)}$, V_{GS} @10V, I_{D} @4.3A<42m Ω
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@3.9A<51m\Omega$
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage	V_{GS}	<u>+</u> 20			
Continuous Drain Current		I _D	4.3	A	
Pulsed Drain Current (Note 4)		I _{DM}	17.2		
Power Dissipation	T _a =25°C	P_{D}	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.5	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_D =4.3A	-	35	42	mΩ
		V_{GS} =4.5V, I_{D} =3.9A	-	44	51	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	Q_g	V _{DS} =20V, I _D =4.3A, V _{GS} =4.5V ^(Note 1,2)	-	4.8	-	nC
Gate-Source Charge	Q_gs		-	1.4	-	
Gate-Drain Charge	Q_gd		-	1.8	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V, f=1.0MHZ	-	410	-	pF
Output Capacitance	Coss		-	50	-	
Reverse Transfer Capacitance	Crss		-	30	-	
Turn-On Delay Time	td _(on)	V_{DD} =20V, I_{D} =3.5A, V_{GS} =10V, R_{G} =1 Ω (Note 1,2)	-	4	-	ns
Turn-On Rise Time	tr		-	30	-	
Turn-Off Delay Time	td _(off)		-	15	-	
Turn-Off Fall Time	tf	R _G =112	-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source		S			4.0	А
Diode Forward Current	l _S		-	-	1.0	
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.78	1.2	V
Reverse Recovery Time	trr	V_{GS} =0V, I_{S} =3.5A dI_{F} / dt =100A/us	-	10.2	-	ns
Reverse Recovery Charge	Qrr		-	5.5	-	nC

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

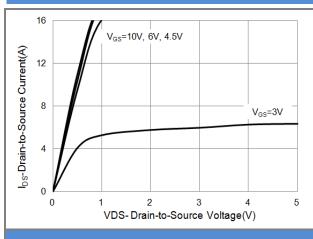


Fig.1 On-Region Characteristics

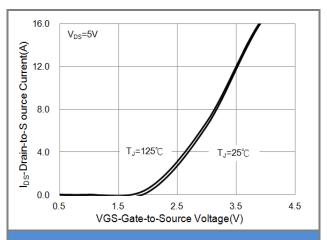


Fig.2 Transfer Characteristics

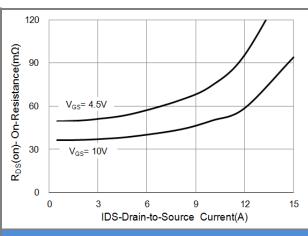


Fig.3 On-Resistance vs. Drain Current

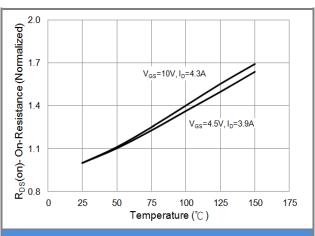


Fig.4 On-Resistance vs. Junction temperature

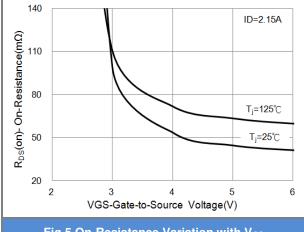


Fig.5 On-Resistance Variation with V_{GS}

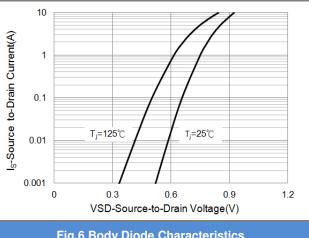


Fig.6 Body Diode Characteristics





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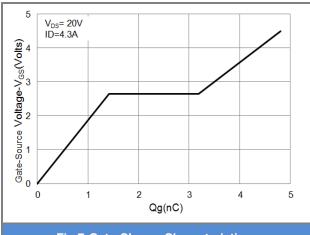


Fig.7 Gate-Charge Characteristics

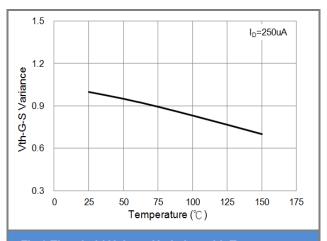


Fig.8 Threshold Voltage Variation with Temperature

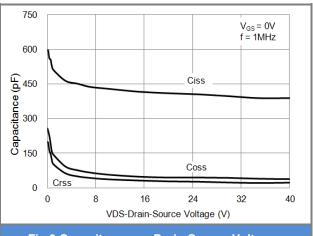


Fig.9 Capacitance vs. Drain-Source Voltage

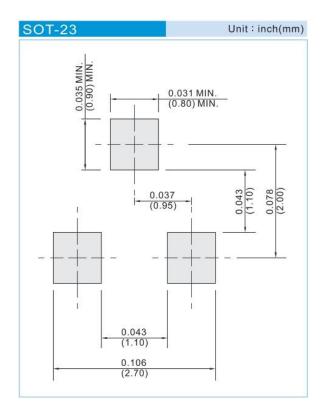




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3440-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A40	Halogen free

Mounting Pad Layout







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